NSN 5961-01-010-5804

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-010-5804 **Inclosure Material:** Metal **Overall Length:** 7.6 millimeters **Overall Diameter:** 2.7 millimeters **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 250.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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